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November 2013



FDD5N50NZ N-Channel UniFETTM II MOSFET **500 V, 4 A, 1.5** Ω

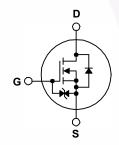
Features

- R_{DS(on)} = 1.38 Ω (Typ.) @ V_{GS} = 10 V, I_D = 2 A
- Low Gate Charge (Typ. 9 nC)
- Low C_{rss} (Typ. 4 pF)
- 100% Avalanche Tested
- · Improved dv/dt Capability
- · ESD Imoroved Capability
- · RoHS Compliant

Applications

- LCD/LED/PDP TV
- Lighting
- · Uninterruptible Power Supply

Π-ΡΔΚ



Description

lasts.

Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

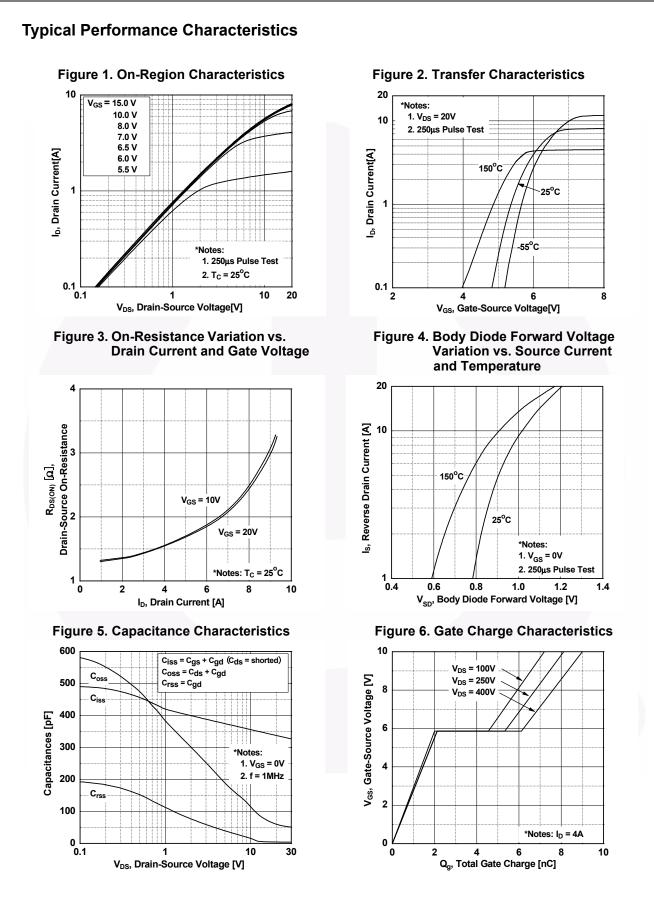
Symbol	Parameter		FDD5N50NZTM	Unit	
V _{DSS}	Drain to Source Voltage		500	V	
V _{GSS}	Gate to Source Voltage			±25	V
	Droin Current	- Continuous (T _C = 25 ^o C)		4	A
I _D	Drain Current	- Continuous (T _C = 100 ^o C)		2.4	
I _{DM}	Drain Current	- Pulsed	(Note 1)	16	А
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		304	mJ	
I _{AR}	Avalanche Current (Note 1)		4	А	
E _{AR}	Repetitive Avalanche Energy (Note 1)		6.2	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		10	V/ns	
P _D	Dewer Dissignation	(T _C = 25°C)		62	W
	Power Dissipation	- Derate Above 25°C		0.5	W/ ^o C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		conds	300	°C

Thermal Characteristics

Symbol	Parameter	FDD5N50NZTM	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	2.0	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	90	0/00

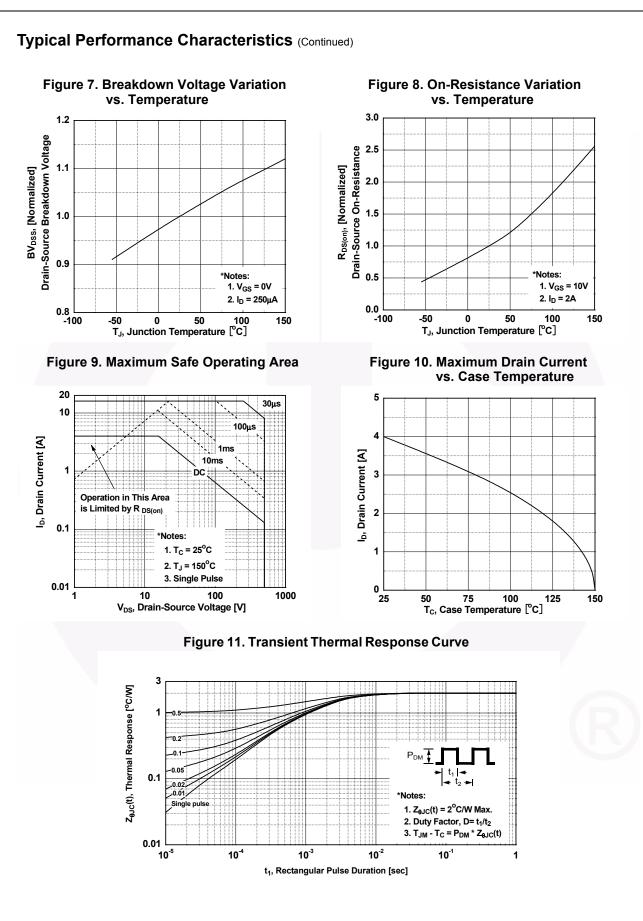
Part NumberTop MarkFFDD5N50NZTMFDD5N50NZ		Package	Packing Method	Reel Size	e T	ape Width	Qu	antity	
		DPAK					2500 units		
Electrica	l Chara	cteristics T _C = 25°C u	unless other	wise noted.					
Symbol		Parameter		Test Condition	s	Min.	Тур.	Max.	Uni
Off Charac	teristics				U				1
BV _{DSS}	Drain to Source Breakdown Voltage		I _D =	I _D = 250 μA, V _{GS} = 0 V, T _J = 25 ^o C		500	-	-	V
ΔBV _{DSS} /ΔTJ		vn Voltage Temperature		250 μA, Referenced	-	-	0.5	-	V/ºC
	Zoro Cot			= 500 V, V _{GS} = 0 V		-	-	1	
IDSS	Zero Gat	e Voltage Drain Current	V _{DS}	= 400 V, T _C = 125°C		-	-	10	μΑ
I _{GSS}	Gate to B	Body Leakage Current	V _{GS}	s = ±25 V, V _{DS} = 0 V		-	-	±10	μA
On Charac	teristics								
V _{GS(th)}	Gate Thr	eshold Voltage	V _G	_S = V _{DS} , I _D = 250 μA		3.0	-	5.0	V
R _{DS(on)}	Static Dra	ain to Source On Resistance	e V _G	_s = 10 V, I _D = 2 A		-	1.38	1.5	Ω
9 _{FS}	Forward	Transconductance	V _{DS}	_s = 20 V, I _D = 2 A		-	3.54	-	S
Dynamic C	haracter	ristics							
C _{iss}	Input Cap	pacitance	V		_{GS} = 0 V,	-	330	440	pF
C _{oss}	Output Ca	apacitance		_s = 25 V, V _{GS} = 0 V, 1 MHz		-	50	70	pF
C _{rss}	Reverse	Transfer Capacitance	I –			-	4	6	pF
Q _{g(tot)}	Total Gate	e Charge at 10V	Vng	$V_{DS} = 400 V I_D = 4 A,$ $V_{GS} = 10 V$ (Note 4)		-	9	12	nC
Q _{gs}	Gate to S	ource Gate Charge				-	2	-	nC
Q _{gd}	Gate to D	orain "Miller" Charge				-	4	-	nC
Switching	Characte	eristics							
t _{d(on)}	Turn-On I	Delay Time				-	12	35	ns
t _r	Turn-On I	Rise Time	V _{DE}	V_{DD} = 250 V, I _D = 4 A, V _{GS} = 10 V, R _G = 25 Ω		-	22	55	ns
t _{d(off)}	Turn-Off	Delay Time	V _G			-	28	65	ns
t _f	Turn-Off I	Fall Time			(Note 4)	-	21	50	ns
Drain-Sou	rce Diode	e Characteristics							
Is	Maximum	Continuous Drain to Source	e Diode For	ward Current		-	-	4	Α
I _{SM}	Maximum Pulsed Drain to Source Diode		de Forward	Forward Current		-	-	16	Α
V _{SD}	Drain to Source Diode Forward Voltage		ge V _G s	V _{GS} = 0 V, I _{SD} = 4 A		-	-	1.4	V
t _{rr}	Reverse F	Recovery Time		$V_{GS} = 0 V, I_{SD} = 4 A,$		-	210	-	ns
Q _{rr}	Reverse Recovery Charge			$dI_{\rm F}/dt = 100 \text{ A}/\mu \text{s}$		-	1.1	· . ·	μC

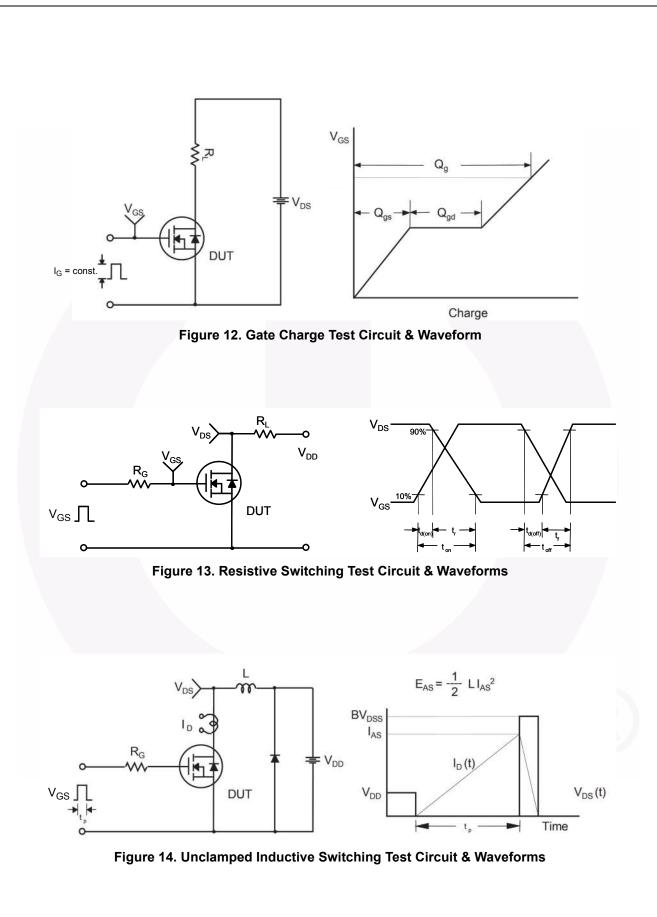
2. L = 38 mH, I_{AS} = 4 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} ≤ 4 A, di/dt ≤ 200 A/µs, V_{DD} ≤ BV_{DSS}, starting T_J = 25°C. 4. Essentially independent of operating temperature typical characteristics.

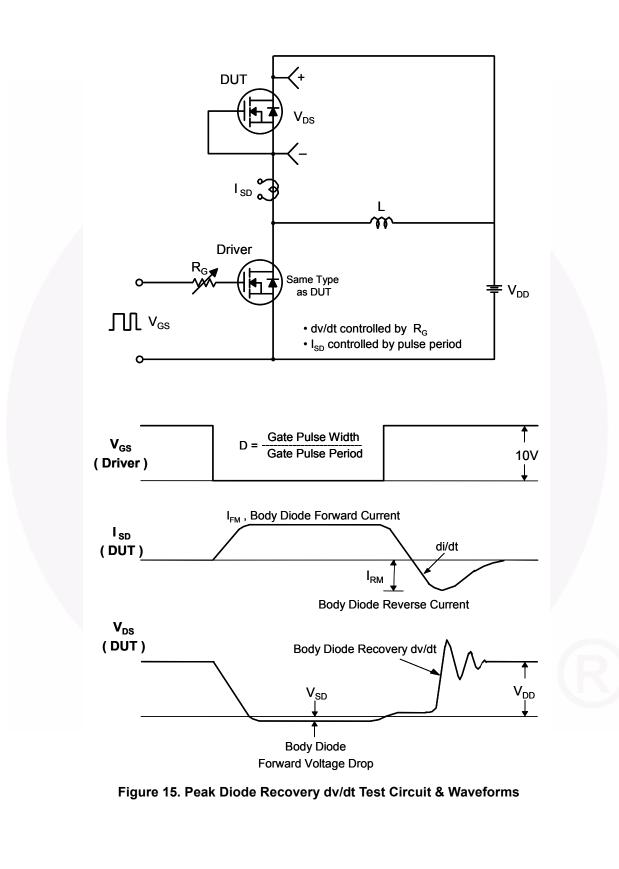


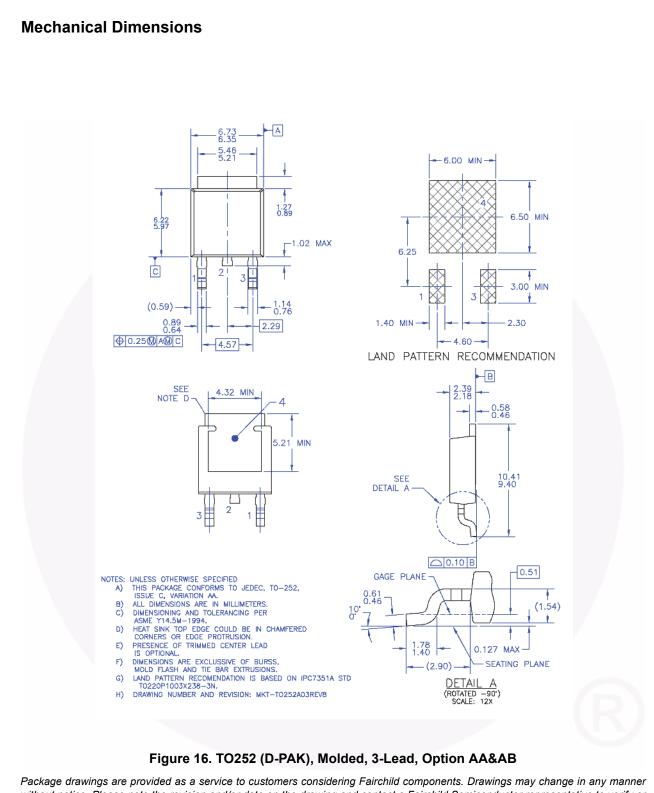
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